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Thermoelectrically polarized amorphous silica promotes sustainable carbon dioxide conversion into valuable chemical products†

Marc Arnau, ^{ab} Isabel Teixidó,^a Jordi Sans, ^{*ab} Pau Turon ^{*c}
and Carlos Alemán ^{*abd}

Electrically polarized amorphous silica (aSiO₂) is demonstrated to be an efficient and viable metal-free heterogeneous catalyst for the conversion of CO₂ into valuable chemical products. The catalyst was prepared applying a thermoelectric polarization process in air to commercially available aSiO₂ nanoparticles. Four polarization temperatures were assayed (150, 500, 800 and 1000 °C), the larger structural and chemical changes induced by the polarization treatment being observed at 150 and 500 °C. The polarization at such temperatures reduced considerably the electrical resistance of calcined aSiO₂, while no significant change was detected at 800 and 1000 °C. Polarized aSiO₂ was tested as heterogeneous catalysts for the reaction of CO₂ with water at mild reaction conditions (120 °C, 6 bar of CO₂, 40 mL of water, 72 h). The highest catalytic activity was observed with aSiO₂ polarized at 150 °C, which was attributed to the structural defects induced during the thermoelectric polarization treatment. Thus, CO₂ was converted into a mixture of formic acid (39.9%), acetic acid (44.4%) and dioxane (15.7%). Although the catalytic process was not selective, the yields were not only very high but also allowed obtaining a significant amount of dioxane, a product with four carbon atoms, which is very unusual in processes catalyzed by polarized ceramics. In summary, polarized aSiO₂ can be used as a sustainable and low-cost raw material to prepare metal-free catalysts by means of a thermoelectric polarization process at 150 °C. This catalyst is capable of capturing CO₂ to produce valuable chemical products by applying mild reaction conditions.

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Introduction

Hydroxyapatite (HAP) is a naturally occurring calcium phosphate, Ca₁₀(PO₄)₆(OH)₂, and a major component of bones and teeth. Among other applications, HAP has been long used in hard tissue engineering applications (*e.g.* to repair bone defects, to promote bone augmentation, and to coat human body metallic implants)^{1–4} and as catalyst support material.^{5–8} Semi-permanently and permanently polarized HAP (sp-HAP and p-HAP, respectively), which were obtained by applying a constant voltage at high temperature to samples with

previously generated vacancies (*i.e.* thermoelectric polarization), were found to enhance the electrical properties of HAP by promoting cell activity in tissue engineering applications^{9–11} and by converting the mineral support into a real catalyst,^{12,13} respectively. The main difference between sp-HAP and p-HAP comes from the conditions used for the thermoelectric polarization process and the previous calcination step.¹⁴ Thus, a water vapor atmosphere during the calcination step and the application of relatively low temperatures (<800 °C) and/or low voltages (≤300 V) result in reversible structural distortions,¹⁵ while the calcination in air and the polarization using a high temperature (≥800 °C) and a high voltage (≥500 V) result in structural reorganizations and re-orientations that remain for a long time (>3 months).^{15,16}

Thermoelectric polarization has also been applied to other ceramics and, even, to plastics for energy storage and sensing.^{17–19} In the field of catalysis, some attempts have been performed to improve the behavior of electrocatalysts. For example, Xia *et al.*²⁰ used a multi-electric field polarization method to produce nitrogen–iron functionalized carbon nano-catalyst electrodes. In another example, Vijay *et al.*²¹ used polarized Bi–Fe–O electrocatalysts to improve the performance of the oxygen evolution reaction. However, thermoelectric

^aIMEM-BRT Group, Departament d'Enginyeria Química, EEBE, Universitat Politècnica de Catalunya – BarcelonaTech, C/Eduard Maristany, 10-14, 08019, Barcelona, Spain. E-mail: jordi.sans.mila@upc.edu; carlos.aleman@upc.edu

^bBarcelona Research Centre in Multiscale Science and Engineering, Universitat Politècnica de Catalunya – BarcelonaTech (UPC), Av. Eduard Maristany, 16, Barcelona 08019, Spain

^cB. Braun Surgical, S.A.U. Carretera de Terrassa 121, 08191 Rubí, Barcelona, Spain. E-mail: pau.turon@bbraun.com

^dInstitute for Bioengineering of Catalonia (IBEC), The Barcelona Institute of Science and Technology, Baldri Reixac 10-12, 08028 Barcelona, Spain

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polarization has not been used to generate new catalysts from non-catalytic materials. In this work, we are focused on the transformation of a conventional non-catalytic material, amorphous silica (aSiO₂), into a powerful permanently polarized catalyst able to promote the fixation of carbon dioxide (CO₂), as we did with HAp.²² Thus, the properties of aSiO₂, are expected to be modifiable by altering the atomic arrangement through physical treatments, as has been observed for other amorphous nanomaterials.^{23,24}

aSiO₂ is a commonly used material due to its low-cost, exceptional thermal stability, high melting point, and insulating properties.²⁵ Although aSiO₂ can be extracted from natural sources, synthetic aSiO₂ is one of the most produced nanomaterials, with a worldwide production in millions of tons per year.²⁶ It has wide application in glass manufacturing,^{27,28} electronics,^{29,30} ceramics,^{31,32} food industry,³³ cosmetics,³⁴ and as a filler in various materials.^{35,36} Although aSiO₂ has also been extensively used as catalyst support,^{37–42} only metal-doped aSiO₂ shows catalytic properties.^{43–46} In this work, we transform aSiO₂ into an intrinsic metal-free catalyst applying the thermoelectric polarization process. This latter process promotes the catalytic activity of this naturally-occurring ceramic at moderate temperatures and pressures (120 °C and 6 bar), allowing the conversion of CO₂ into formic acid, acetic acid and dioxane.

The work is organized as follows. After the Methods section, the first part of the Results and discussion section has been aimed to ascertain the influence of the calcination and polarization temperatures (*T*) in the properties of calcined and thermoelectrically polarized aSiO₂ samples. For this purpose, the following temperatures were considered: *T* = 150, 500, 800 or 1000 °C. Distinctive properties have been found for aSiO₂ polarized at *T* = 150 °C and, to a lesser extent, for aSiO₂ polarized at *T* = 500 °C, suggesting that such materials may behave as catalysts. In the second part of the Results and discussion section, the catalytic activity of the aSiO₂ polarized at *T* = 150, 500, 800 or 1000 °C has been evaluated. Results show that aSiO₂ polarized at *T* = 150 °C presents the highest efficiency to convert CO₂ into valuable chemical products, indicating that such material can be considered a high performance, sustainable and low-cost metal-free catalyst.

Methods

Sample preparation

aSiO₂ nanopowder (Sigma Aldrich; spherical, 5–20 nm particle size, and 99.5% trace metal basis) was dry at 150 °C for 1 h and, subsequently, was compressed into discs (13 and 0.7 mm of diameter and thickness, respectively) using a Specac Manual hydraulic press of 15 tons equipped with an Specac Evacuable Pellet Die. The discs obtained were brittle and consequently were handled with great care for the characterization and catalysis tests.

A half of the prepared aSiO₂ discs were introduced into a ceramic holder and calcined using a Carbolite ELF11/6B/301 muffle furnace with a temperature range from 0 °C to 1100 °C. Hereafter, the calcined samples have been denoted *c-T/aSiO₂*, where *T* values of 150 °C (*c-150/aSiO₂*), 500 °C (*c-500/aSiO₂*),

800 °C (*c-800/aSiO₂*) and 1000 °C (*c-1000/aSiO₂*) were considered. The calcination process took 2 h : 1 h to heat the system to the desired temperature and 1 h in which the system was maintained at that temperature. Finally, samples were allowed to cool down without applying any control ramp.

The rest of the prepared aSiO₂ discs were subjected to the thermoelectric polarization process. For this purpose, samples were placed inside the muffle furnace that was heated at the desired temperature value, while an electric voltage of 500 V was applied by connecting a GAMMA voltage source (with a voltage range of 0 kV to 50 kV) to two stainless steel AISI 304 electrodes using platinum wires. Electrodes were separated by a 2 cm ceramic piece. The thermoelectric polarization process took 2 h : 1 h to heat the system to the desired temperature and 1 h in which the system was maintained at that temperature. After that time, polarized samples were allowed to cool down maintaining the applied electric field for 30 min, and finally, all the system was powered off and left to cool down overnight without applying any control ramp. Hereafter, polarized samples, have denoted *p-T/aSiO₂*, where *T* values of 150 °C (*p-150/aSiO₂*), 500 °C (*p-500/aSiO₂*), 800 °C (*p-800/aSiO₂*) and 1000 °C (*p-1000/aSiO₂*) were considered.

The calcination and polarization temperatures were carefully chosen. The temperature of 150 °C was selected to facilitate the evaporation of the considerable amount of absorbed water present in aSiO₂ nanopowder, while the temperatures of 500 °C, 800 °C and 1000 °C were specifically settled on because they are close to the transition temperatures between SiO₂ polymorphs.

N₂-physisorption measurements were conducted in the TriStar II3020-Micrometrics analyzer at liquid nitrogen temperature. Prior to the measurements, the samples were degassed at 90 °C for 1 h. The Brunauer–Emmett–Teller (BET) method was applied to calculate the BET surface area for a relative pressure (*P/P₀*) range of 0.05–0.3. The average pore size was determined by applying the Barrett–Joyner–Halenda (BJH) method to the desorption branch of the isotherms. The total pore volume was determined from the maximum adsorption value at *P/P₀* = 0.997. Temperature-programmed reduction.

Characterization

Raman analyses of *c-T/aSiO₂* and *p-T/aSiO₂* discs were performed using an inVia Qontor confocal Raman microscope (Renishaw) equipped with a Renishaw Centrus 2957T2 detector and a 532 nm laser. In order to obtain representative data, 32 single point spectra were averaged.

FTIR spectra of nanopowder samples were recorded on a FTIR Nicolet 6700 spectrophotometer from Thermo Scientific through transmission accessory. Potassium Bromide (KBr) pellets mixed with grinded *c-T/aSiO₂* or *p-T/aSiO₂* powder were assembled. Samples were evaluated using the spectra manager software. For each sample, 64 scans were performed between 4000 and 400 cm⁻¹ with a resolution of 4 cm⁻¹.

Ultraviolet-visible (UV-vis) absorption spectra of the prepared discs were obtained using a Shimadzu UV-3600 equipment. The UV-vis spectra presented a total wavelength range of 185–3300 nm with a resolution of 0.1 nm. The



equipment was operated using an integrating sphere ISR-3100 accessory with an inner diameter of ~60 mm PMT and PbS sensors. The optical range of the accessory was 200–2600 nm.

Detailed inspection of calcined and polarized samples was conducted by scanning electron microscopy (SEM). A Focus Ion Beam Zeiss Neon 40 instrument (Carl Zeiss, Germany) equipped with an energy dispersive X-ray (EDX) spectroscopy system and operating at 5 kV was used. The diameter of the nanoparticles was measured with the ImageJ software ($n = 100$).

X-ray photoelectron spectroscopy (XPS) analyses were conducted to determine the chemical state and atom composition of samples using a SPECS ultra-high vacuum multi-chamber system. The spectrometer was equipped with a high-intensity twin-anode XR-50 X-ray source of Mg/Al (1253 eV/1487 eV) operating with the Al anode at 150 W, positioned perpendicular to the analyzer axis, and utilizing a Phoibos 150 EP hemispherical energy analyzer with a MCD-9 detector. The stage position was digitally controlled to ensure consistency throughout the analysis. The pass energy of the hemispherical analyzer was set at 25 eV, and the energy step for high-resolution spectra was set at 0.1 eV. The pressure in the analysis chamber was maintained below 10^{-7} Pa, and binding energy (BE) values were referred to the C 1s peak at 284.5 eV. Data were processed using CasaXPS software (Casa Software Ltd, UK).

Wide angle X-ray diffraction (XRD) patterns were obtained using a Bruker D8 Advance model with Bragg–Brentano 2θ configuration and Cu K_α radiation ($\lambda = 0.1542$ nm). A one-dimensional Lynx Eye detector was employed. Measurements were performed in a 2θ range of $5\text{--}70^\circ$ in steps of 0.02° , and scan speed of 2 s.

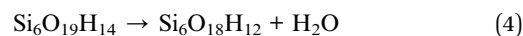
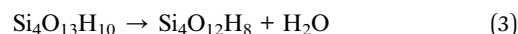
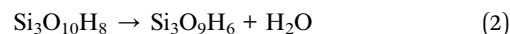
Electrochemical impedance spectroscopy (EIS) studies were performed using a VIONIC Autolab from Metrohm connected to a conductivity meter cell by means of two stainless steel electrodes AISI 304 isolated by a resin holder.⁴⁷ Measurements were performed in the 100 kHz to 10 mHz frequency range and applying a 100 mV sinusoidal voltage.

Theoretical calculations

n -Membered-tetrahedral SiO_2 rings/chains were assembled and pre-optimized using Avogadro software⁴⁸ auto optimization tool with MMFF94 force field and steepest descent algorithm to ensure structural conformation energy minimization before Density Functional Theory (DFT) optimization. DFT calculations were performed using Gaussian 16 software suite⁴⁹ with the B3LYP⁵⁰ functional and 6-311G++(d,p)^{51,52} basis set for accurately describing Si atoms. After structure optimization, enthalpies for the different compounds were calculated based on harmonic vibrational frequencies and used for strain energy (E_{strain}) estimation following the formula:

$$E_{\text{strain}} = \left(\Delta_f H_{\text{ring}}^\circ + \Delta_f H_{\text{water}}^\circ \right) - \Delta_f H_{\text{chain}}^\circ \quad (1)$$

More specifically, the processes used to estimate E_{strain} , which involved n -membered-tetrahedral SiO_2 rings/chains with $n = 3, 4$ and 6 (eqn (2)–(4)), were:



CO₂ conversion reactions

The batch CO₂ conversion into valuable chemicals was carried out using a reactor that consisted of an inert reaction chamber (120 mL) coated with a perfluorinated polymer where both the catalyst and water were placed. All surfaces were coated with a thin film of perfluorinated polymer in order to avoid any contact between the reactants and catalyst and the stainless steel reactor surfaces, in order to discard other catalytic effects. The reactor was equipped with an inlet valve for the entrance of gases and an outlet valve to recover the gaseous reaction products.

Both the p - T/aSiO_2 catalysts and de-ionized liquid water (40 mL) were introduced into the reactor. After exhaustive purge with CO₂, the chamber pressure was increased up to 6 bar of CO₂ (measured at room temperature). The reaction was conducted for 72 h (3 days) at 120 °C. Control reactions were performed using c - T/aSiO_2 discs as catalysts. All processes were performed in triplicate.

Analysis of the reaction products

The reaction products dissolved in the liquid water and the reaction products adsorbed on the catalyst were analyzed by ¹H NMR spectroscopy. In order to desorb the reaction products from the catalyst, samples were dissolved in 1 mL of a solution containing 100 mM of HCl and 50 mM of NaCl with the final addition of deuterated water. All ¹H NMR spectra were acquired with a Bruker Ascend 400 spectrometer operating at 400.1 MHz. The chemical shift was calibrated using tetramethylsilane as internal standard. 256 scans were recorded in all cases. In order to compare the different products obtained from the studied reactions, the areas associated to the proton contribution were normalized and calibrated through external references.

Results and discussion

Characterization of c - T/aSiO_2 and p - T/aSiO_2

Fig. 1a shows the Raman spectra of c - T/aSiO_2 samples prepared using $T = 150$ °C, 500 °C, 800 °C and 1000 °C. Samples display broad bands at 800 cm^{-1} (O–Si–O asymmetric vibrations), 980 cm^{-1} (superficial Si–OH group), and 1179 cm^{-1} (SiO_4 asymmetric vibrations).^{53–55} The bands below 650 cm^{-1} , which are typically ascribed to the structural defects of the aSiO_2 matrix in the form of n -membered-tetrahedral rings (D2, D1 and R bands for $n = 3, 4$ and 6 respectively), appear at 607, 493 and 445 cm^{-1} , respectively.⁵⁶ According to the literature,⁵⁴ the relative amplitudes of both the 980 and 493 cm^{-1} bands decreases with the decrease of the specific surface area. As it can be seen, the intensity and amplitude of such bands in c - T/aSiO_2



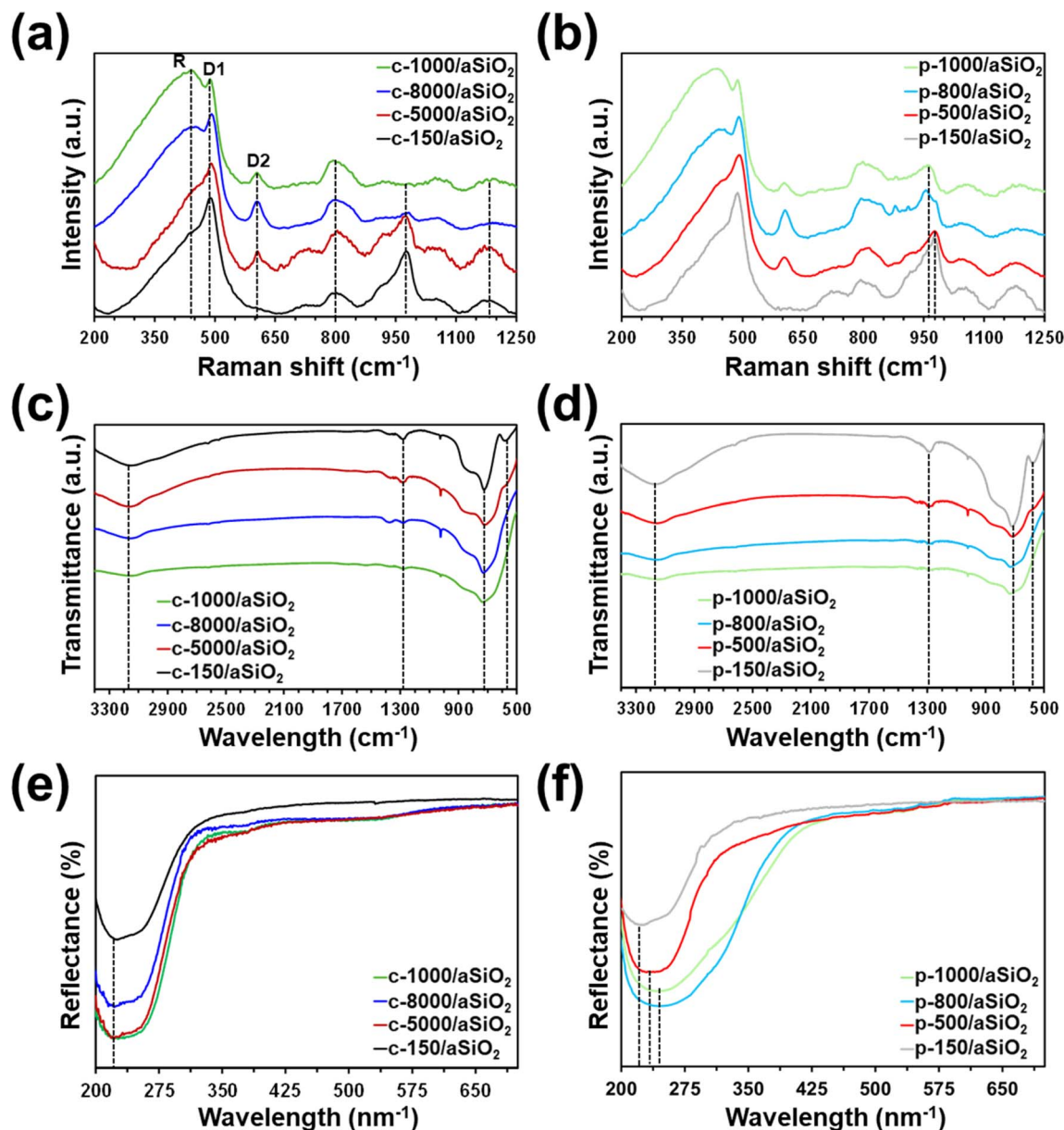


Fig. 1 (a and b) Raman, (c and d) FTIR and (e and f) UV-vis spectra of (a, c and e) *c-T/aSiO₂* and (b, d and f) *p-T/aSiO₂* prepared using $T = 150$ °C, 500 °C, 800 °C and 1000 °C.

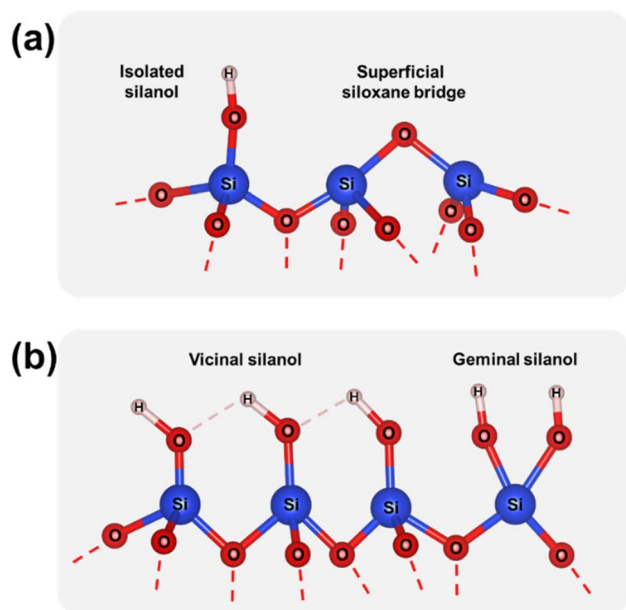
decreased with increasing calcination temperature, being practically inexistent for *c-1000/aSiO₂*. On the other hand, the intensity of the bands at 607 and 445 cm^{-1} , which were shoulders for *c-150/aSiO₂* increased with the calcination temperature. All such variations suggested that, after the initial dehydration process at 150 °C, the calcination at higher temperatures tended to re-organize the structural network promoting rings with $n = 3$ and 6.

The Raman spectra collected for *p-T/aSiO₂* for $T = 150$ °C, 500 °C, 800 °C and 1000 °C are shown in Fig. 1b. For all the considered temperatures, the spectrum was similar to that achieved for the corresponding *c-T/aSiO₂* sample (Fig. 1a). The most noticeable difference between the spectra of *p-T/aSiO₂* and *c-T/aSiO₂* was detected in the symmetric stretch vibrations of

silanols (Si-OH group). While this band practically disappeared in *c-800/aSiO₂* and *c-1000/aSiO₂*, suggesting that the superficial silanol groups transformed into superficial siloxane bridges (Scheme 1a), it shifted to approximately 960 cm^{-1} in *p-800/aSiO₂* and *p-1000/aSiO₂*, suggesting a structural reorganization of the hydroxyls, as observed for *p-HAP*.¹⁵ This blue shift may be due to the effect of such rearrangement in the hydrogen bonding structure, which changed from a vicinal silanol groups to geminal silanol groups (Scheme 1b).

DFT calculations on systems involving n -membered-tetrahedral SiO_2 rings/chains with $n = 3, 4$ and 6, which are depicted in Fig. 2a, allowed us to determine the strain energy (eqn (1)) as a function of the size of the ring by using the isodesmic reactions displayed in eqn (2)–(4). The lowest strain





Scheme 1 (a) Superficial silanol groups and siloxane bridges. (b) Vicinal and geminal silanol groups.

energy ($5.0 \text{ kcal mol}^{-1}$) was obtained for $n = 4$ (Fig. 2b), which is consistent with the fact that the intensity of the D1 band is much higher than those of D2 and R bands for c -150/aSiO₂ and p -150/aSiO₂. The strain energy of the rings with $n = 3$ and 6 was predicted to be 18% and 54% higher than the one obtained for $n = 4$. These results are in good agreement with the fact that the D2 band gains intensity for samples prepared using $T \geq 500 \text{ }^\circ\text{C}$, while the R band is only clearly identified for samples obtained using $T \geq 800 \text{ }^\circ\text{C}$. Accordingly, the thermal energy provided during the calcination and polarization processes allowed to overcome the energy threshold that defines the strain of the rings, which depends on the size of the ring.

Unfortunately, FTIR spectra of c - T /aSiO₂ and p - T /aSiO₂ samples (Fig. 1c and d) only showed broad bands and did not provide unambiguous information. The spectra of c - T /aSiO₂

reflected the presence of surface Si-OH groups by the hydroxyl band at 3150 cm^{-1} . However, the intensity of such band drastically decreased with increasing calcination temperature (Fig. 1c), confirming Raman observations. The Si-O bond appeared at 1287 cm^{-1} , the broad band at 725 was attributed at the O-Si-O and Si-O-Si vibration.^{57,58} The peak at 575 cm^{-1} , which consistently decreases with increasing temperature, was ascribed to the Si-OH stretching.^{57,58} Bands at the same positions and similar trends (*i.e.* the bands associated to Si-OH groups decreased with increasing polarization temperature) were observed for p - T /aSiO₂ (Fig. 1d).

UV-vis spectra evidenced that the absorbance of c - T /aSiO₂ at $\lambda = 223 \text{ nm}$ increased when $T > 150 \text{ }^\circ\text{C}$ (Fig. 1e), suggesting a change in the size and/or morphology of the SiO₂ nanoparticles. However, although changes in nanoparticle size of calcined c - T /aSiO₂ were confirmed by SEM micrographs (Fig. 3a and S1†), inspection to the average size (Table 1; histograms shown in Fig. S2†) did not provide any clear correlation with the absorbance. On the other hand, the absorption peak of p - T /aSiO₂ not only increased with the polarization temperature but also shifted from $\lambda = 223 \text{ nm}$ (p -150/aSiO₂) to $\lambda = 235 \text{ nm}$ (p -500/aSiO₂) and 247 nm (p -800/aSiO₂ and p -1000/aSiO₂). Similarly, although the size of p - T /aSiO₂ nanoparticles changed with the polarization temperature (Fig. 3b and S3†), no correlation between the average size (Table 1) and the absorbance was found. Accordingly, the change in absorbance, including the absorption at lower λ values, cannot be due only to a variation in the size of the nanoparticles but is possibly accompanied by a chemical restructuring.

To further investigate changes in absorbance, possible chemical changes induced by the calcination and polarization treatments were studied by XPS. The acquired survey scans, which are displayed in Fig. S4,† allowed us to identify well-defined peaks of Si 2p, O 1s and C 1s for all studied samples. The atomic composition determined from XPS measurements is shown in Table 2. Carbon residues result from impurities in commercial aSiO₂ nanoparticles and from hydrocarbon impurities adsorbed during their manipulation. The intensity of the C 1s peak decreased with increasing calcination and

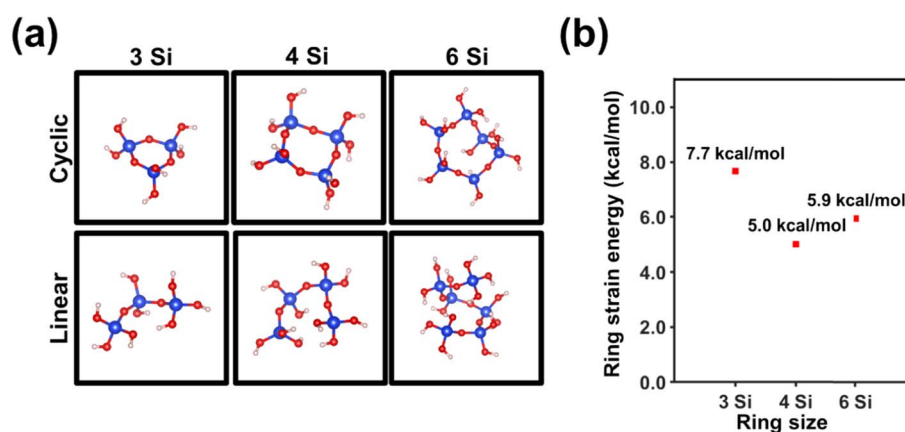


Fig. 2 (a) DFT optimized structures of systems involving n -membered-tetrahedral SiO₂ rings/chains with $n = 3, 4$ and 6. (b) Variation of the strain energy with the size of the ring.



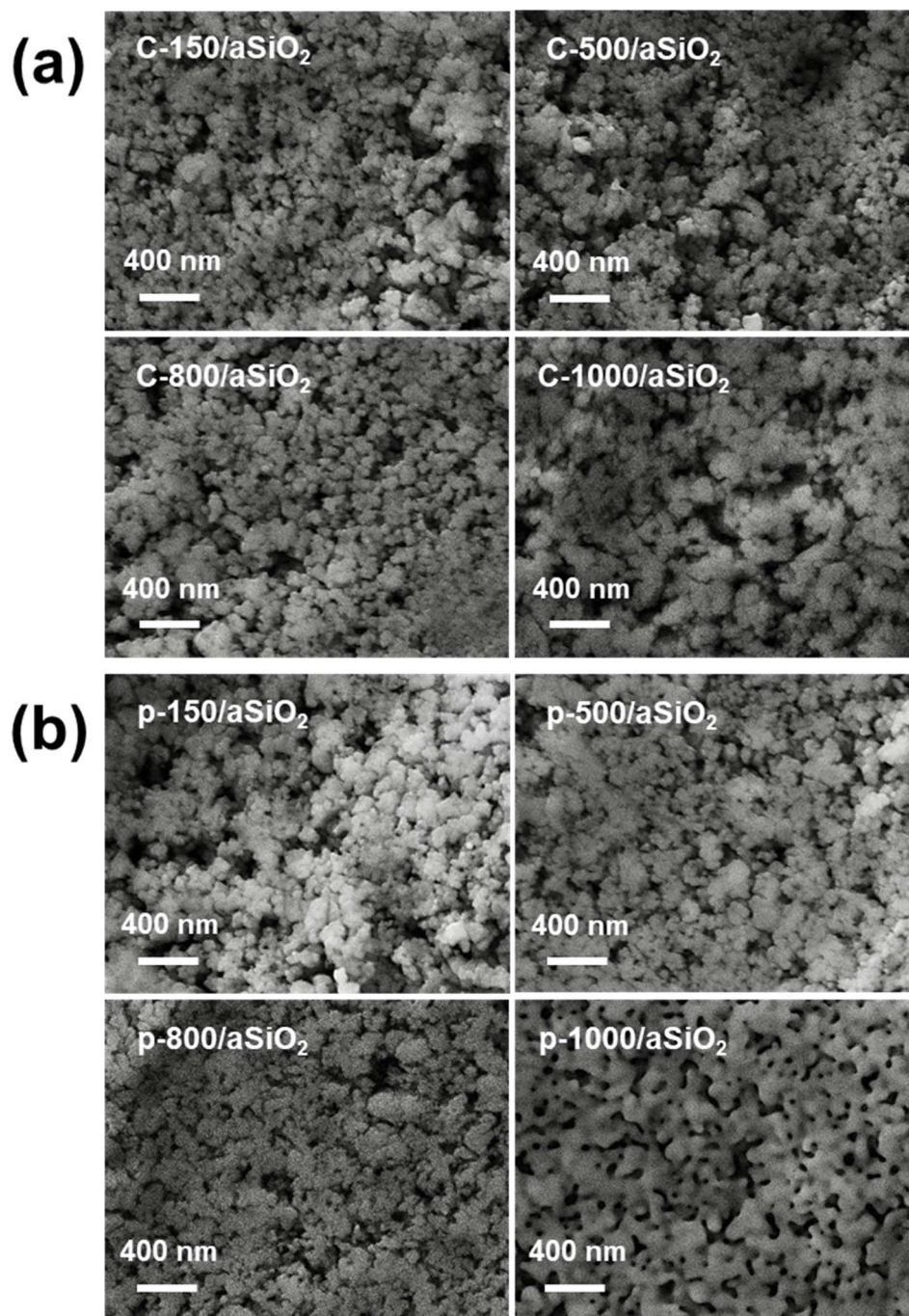


Fig. 3 Representative SEM micrographs of (a) c-*T*/aSiO₂ and (b) p-*T*/aSiO₂.

Table 1 Average size of c-*T*/aSiO₂ and p-*T*/aSiO₂ nanoparticles

Calcined samples	Average size (nm)	Polarized samples	Average size (nm)
c-150/aSiO ₂	67.6 ± 12.4	p-150/aSiO ₂	51.0 ± 12.3
c-500/aSiO ₂	58.2 ± 8.8	p-500/aSiO ₂	46.1 ± 8.8
c-800/aSiO ₂	48.8 ± 9.0	p-800/aSiO ₂	31.0 ± 9.2
c-1000/aSiO ₂	54.7 ± 12.1	p-1000/aSiO ₂	65.4 ± 12.1



Table 2 Atomic composition (%) of *c-T/aSiO₂* and *p-T/aSiO₂* samples

Sample	Si 2p	O 1s	C 1s	O 1s/Si 2p
c-150/aSiO ₂	26.9	43.6	29.5	1.62
c-500/aSiO ₂	34.9	51.6	13.5	1.48
c-800/aSiO ₂	36.5	53.7	9.8	1.43
c-1000/aSiO ₂	40.3	54.5	5.2	1.35
p-150/aSiO ₂	26.3	44.5	29.2	1.69
p-500/aSiO ₂	35.5	54.9	9.6	1.54
p-800/aSiO ₂	35.4	52.7	11.9	1.49
p-1000/aSiO ₂	37.8	53.5	8.7	1.42

polarization temperatures, indicating that carbon impurities were eliminated during such processes. This peak does not affect the interpretation of the results. Indeed, the C 1s peak was actually used for binding energy calibration by setting its value to 284.8 eV to correct surface charging.

Interestingly, the O 1s/Si 2p ratio, was systematically found to decrease with increasing calcination and polarization temperatures for *c-T/aSiO₂* and *p-T/aSiO₂*, respectively (Table 2). For both *c-T/aSiO₂* and *p-T/aSiO₂* such ratio decreased by around 16% when the temperature increased from 150 °C to 1000 °C, which evidenced significant chemical changes during the calcination and polarization processes. These chemical changes, which may go beyond the change in size of the tetrahedral *n*-membered rings and the reduction of superficial Si-OH groups observed by Raman microscopy, suggest the elimination of oxygen atoms and their potential replacement by silicon atoms.

Fig. 4 shows the high resolution XPS spectra for Si 2p of *c-T/aSiO₂* and *p-T/aSiO₂*. From the Si 2p spectra of *c-T/aSiO₂* and *a-T/aSiO₂* four sub-peaks centered at 106.8, 106.1, 104.5, and

103.8 eV are observed (named A–D in Fig. 4). According to the literature, such peaks may be assigned to the partial replacement of the oxygen atoms from the tetrahedral structure by Si atoms.^{59,60} Thus, A–D sub-peaks could be associated to Si⁴⁺ (Si–O from Si–O₄), Si³⁺ (Si–O from Si–Si–O₃), Si²⁺ (Si–O from Si₂–Si–O₂) and Si¹⁺ (Si–O from Si₃–Si–O), respectively.^{59,60} This interpretation is consistent with the O 1s peak, which does not display any broadening (as the Si–O bond is not directly affected by such substitution) but only a shift with increasing calcination and polarization temperatures (Fig. S5†). Another explanation for the four peaks derived from the Si 2p signal, and which would be in agreement with the Raman spectra shown in Fig. 1a and b, would be the formation of structural defects involving *n*-membered tetrahedral rings. This could also explain the shift of the O 1s signal from 533.2 eV (*c*-150/aSiO₂ and *p*-150/aSiO₂) to 531.7/531.9 eV (*c*-500/aSiO₂/*p*-500/aSiO₂), 533.5/532.9 eV (*c*-800/aSiO₂/*p*-800/aSiO₂) and 531.7/531.4 eV (*c*-1000/aSiO₂/*p*-1000/aSiO₂). Thus, since the change in ring size, as determined by Raman spectroscopy, affects the neighboring chemical environment but not directly the Si–O bond, there would be a shift of the O 1s peak without broadening.

The variation in the distributions of the four deconvoluted Si 2p peaks with calcination and polarization temperatures (Table S1†) suggests that the *c-T/aSiO₂* and *p-T/aSiO₂* samples follow a pattern resembling that observed in the Raman spectra (Fig. 1a and b). For example, while D showed the highest percentage for *c*-150/aSiO₂, *p*-150/aSiO₂ and *p*-500/aSiO₂, B was the most populated for the rest of the samples. This similarity between the results obtained by XPS and Raman spectroscopy supports the hypothesis that, after dehydration, the distribution of *n*-membered tetrahedral rings tends to reorganize. According to the literature, such re-organizations are crucial to reach a thermodynamically stable configuration resulting in the permanently polarized state.¹⁹ Certainly, this work reports one of the first experimental evidences supporting the polarization mechanism proposed. Overall, the non-systematic variation of the absorbance in *c-T/aSiO₂* and *p-T/aSiO₂* samples as a function of the calcination and polarization temperatures (Fig. 1e and f) was due to a combination of two factors: (1) the change in the size of the nanoparticles due to the calcination and polarization treatment, described above (Fig. 3; Table 1); and (2) the change in the chemical structure associated to the reorganization of *n*-membered rings.

Fig. 5a and b shows the XRD patterns of *c-T/aSiO₂* and *p-T/aSiO₂*. The characteristic diffraction broad peak centered at around 24° confirmed that nanoparticles remained amorphous after the calcination and polarization treatments, independently of the temperature applied during such treatments. Thus, while the thermoelectric polarization process was found to increase the crystallinity of calcined HAP (c-HAP), even inducing the appearance of new crystalline calcium phosphate phases,^{14,61} the conditions used in this work for such aggressive physical treatment did not practically alter the amorphous organization of aSiO₂.

Electrochemical impedance spectra of *c-T/aSiO₂* samples are shown in Fig. 5c. The resistance of calcined samples increases with the calcination temperature. While the Nyquist plot of *c*-

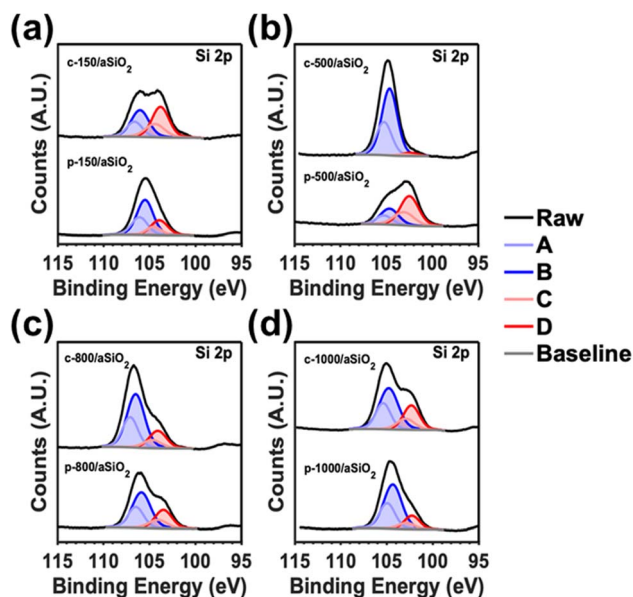


Fig. 4 High resolution Si 2p spectra of: (a) *c*-150/aSiO₂ and *p*-150/aSiO₂; (b) *c*-500/aSiO₂ and *p*-500/aSiO₂; (c) *c*-800/aSiO₂ and *p*-800/aSiO₂; and (d) *c*-1000/aSiO₂ and *p*-1000/aSiO₂.



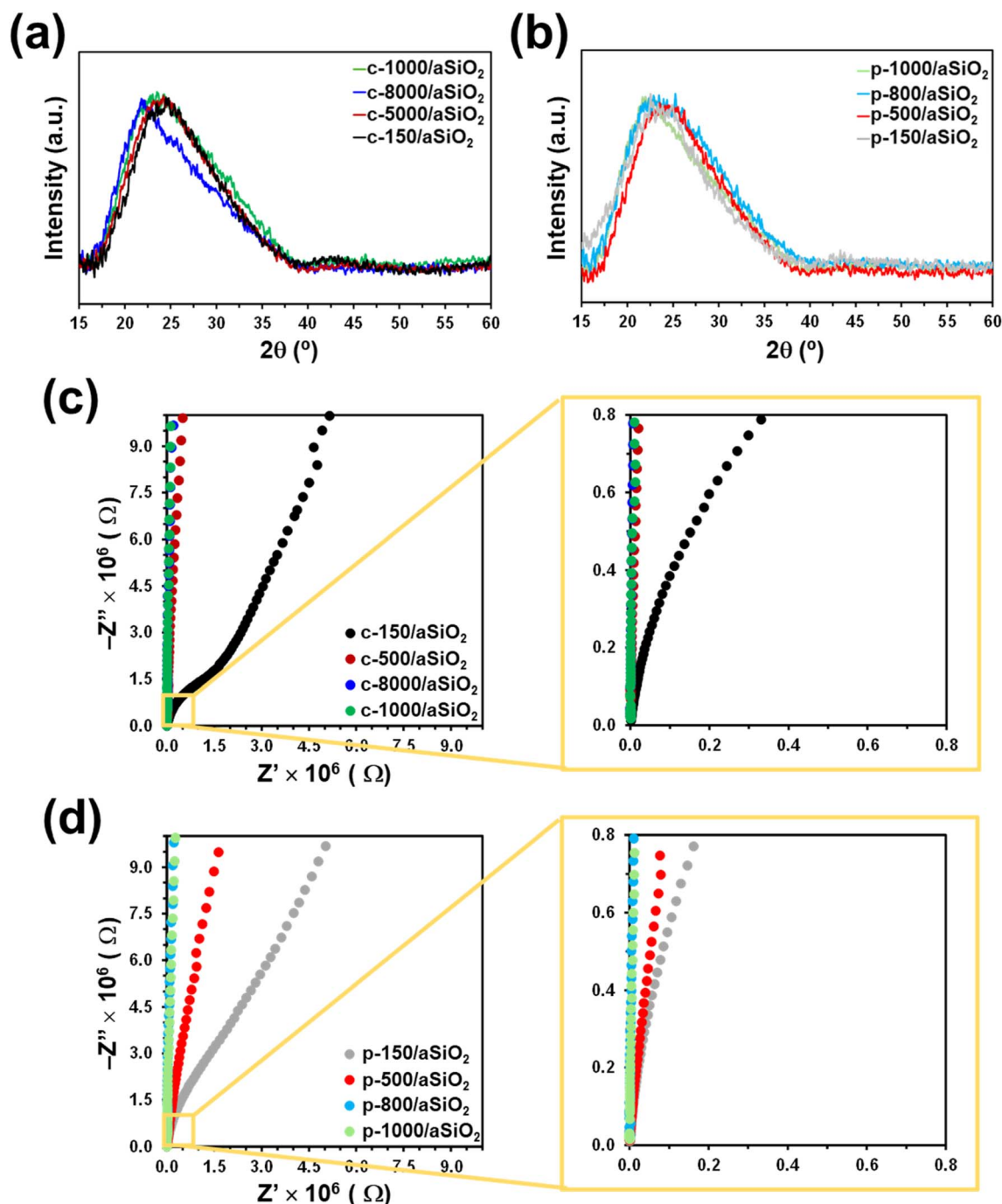


Fig. 5 (a and b) XRD pattern and (c and d) Nyquist plots obtained for (a and c) c - $T/a\text{SiO}_2$ and (b and d) p - $T/a\text{SiO}_2$.

$150/a\text{SiO}_2$ is dominated by a depressed semicircle and a straight line, which correspond to the resistance and the capacitance, respectively, the resistance of the discs calcined using temperatures equal or higher than $500\text{ }^\circ\text{C}$ suffered a significant increase. A similar effect was observed for p - $T/a\text{SiO}_2$ (Fig. 5d), even though in this case the semicircle was observed for p - $150/a\text{SiO}_2$ and p - $500/a\text{SiO}_2$ while p - $800/a\text{SiO}_2$ and p - $1000/a\text{SiO}_2$ displayed the highest resistance. Considering that in this work the objective of the thermoelectric treatment was to polarize the $a\text{SiO}_2$ so that it acts as a catalyst, the EIS spectra indicate that

this was only achieved when the polarization temperature is $150\text{ }^\circ\text{C}$ and, to a lesser extent, at $500\text{ }^\circ\text{C}$.

The thermoelectric polarization of HAp to produce p -HAp resulted not only in significant structural changes (*i.e.* the crystallinity increased and a brushite-like domains appeared at the outer surface layer due to the re-orientation of the OH^- groups⁶¹) but also in an enhancement of the electrical properties, which was attributed to the controlled generation of vacancies, the specific orientation of the remaining OH^- groups and the surface charge accumulation.¹⁵ Both structural and



electrical changes were maximum when p-HAp was obtained using a calcination and polarization temperature of 1000 °C, the material derived from such conditions showing the best performance as catalyst in CO₂ conversion reactions. Although the structure and polarization mechanisms of HAp and aSiO₂ are very different and, consequently, not comparable, it is expected that in both cases the greatest catalytic efficiency corresponds to the conditions in which the mineral has experienced greater structural and electrical changes. In this work, the maximum changes have been obtained when aSiO₂ has been treated using calcination and polarization temperatures of 150 °C and, to a lesser extent, of 500 °C. According to these observations, it can be anticipated that the catalytic performance of p-150/aSiO₂ should be better than that of p-500/aSiO₂, which in turn should be much better than those of p-800/aSiO₂ and p-1000/aSiO₂.

Catalytic fixation of CO₂ using p-T/aSiO₂

The efficiency of c-T/aSiO₂ (control) and p-T/aSiO₂ as catalysts to convert CO₂ into valuable chemical products was examined using a batch reaction with 6 bar of CO₂ and 40 mL at 120 °C for 72 h. The reaction products were evaluated by ¹H-NMR, quantifying the amount of product dissolved in the liquid water (hereafter named “supernatant”) and adsorbed on the catalyst. Blank reactions were conducted using pristine aSiO₂ (*i.e.* without applying any calcination and/or thermoelectric polarization process) and without any material as catalyst. Reactions

were conducted without applying any external electrical field and UV radiation, as is usual for electrocatalysts and photocatalysts, respectively.

Fig. 6 represents the yield (expressed in μmol of product per gram of catalyst; μmol g_c⁻¹) in the supernatant and the catalyst for each reaction product from CO₂ conversion identified in the processes catalyzed by c-T/aSiO₂ and p-T/aSiO₂, while yield values are listed in Table S2.† It is worth noting that a variety of reactions products with one, two, three and four carbon atoms (usually denoted C1, C2, C3 and C4, respectively) were identified by ¹H NMR: (i) formic acid and methanol as C1; (ii) acetic acid and ethanol as C2; (iii) isopropanol and acetone as C3; and (iv) dioxane as the only C4 product. For both, c-T/aSiO₂ and p-T/aSiO₂, and regardless of the calcination and polarization temperatures, the amount of reaction products dissolved in the supernatant (Fig. 6a) was much higher than the amount of chemicals adsorbed on the solid catalyst (Fig. 6b), where only residual amounts were found.

No reaction product was detected from the blank reaction without catalyst, while the blank reaction using untreated aSiO₂ as catalyst produced residual amounts of acetic acid and acetone (*i.e.* 2.3 ± 0.2 and 0.4 ± 0.2 μmol g_c⁻¹, respectively) in comparison to c-T/aSiO₂ and p-T/aSiO₂, as is shown in Table S2.† On the other hand, the yields obtained in the supernatant were significantly lower for c-T/aSiO₂ controls than for p-T/aSiO₂, even though in both cases the yields were drastically affected by the calcination and polarization temperatures (Fig. 6). These features are clearly evidenced in Fig. 7, which

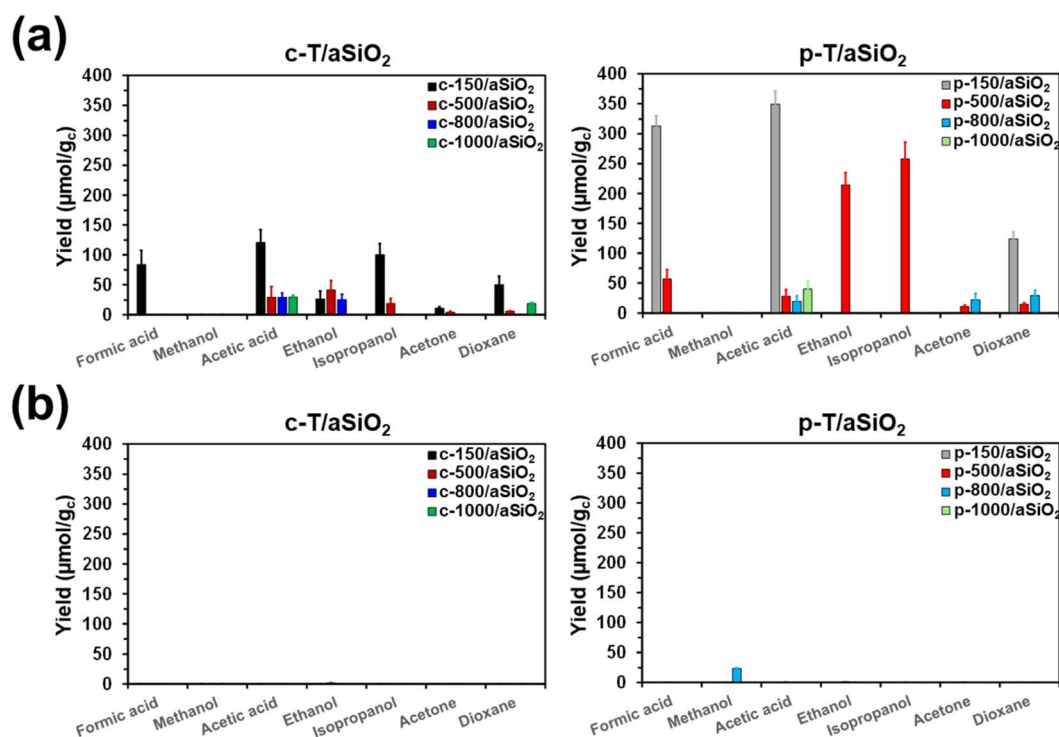


Fig. 6 Variation of the different product yields (a) dissolved in the supernatant and (b) adsorbed in the catalyst from batch reactions catalyzed by c-T/aSiO₂ (left) and p-T/aSiO₂ (right). Reactions were conducted at 120 °C using 6 bar of CO₂ and 40 mL of liquid water. The yields are expressed in μmol of product per gram of catalyst (μmol g_c⁻¹).



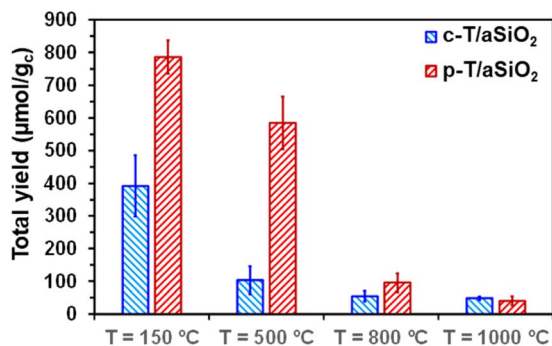


Fig. 7 Total yield (*i.e.* sum of the yields for all the reaction products dissolved in the supernatant and adsorbed on the catalyst) for c-*T*/aSiO₂ and p-*T*/aSiO₂ catalysts.

compares the total reaction yields (expressed as the sum of the yields for all the reaction products) for c-*T*/aSiO₂ and p-*T*/aSiO₂ catalysts.

The highest total reaction yield ($786.3 \pm 50.5 \mu\text{mol g}_c^{-1}$) was obtained for p-150/aSiO₂ (Fig. 7), with the values obtained for c-150/aSiO₂, c-500/aSiO₂, c-800/aSiO₂ and c-1000/aSiO₂ being lower by 50%, 87%, 93% and 94%, respectively. It is worth noting that the drop in the total reaction yield observed for the c-*T*/aSiO₂ samples with increasing calcination temperature was fully consistent with the EIS results, which reflected that the electrical resistance was much higher for the samples prepared using calcination temperatures of 500, 800 and 1000 °C than for c-150/aSiO₂ (Fig. 5c). Similarly, comparison of the results obtained for the different polarized samples indicates that the total yield decreased with increasing polarization temperature (Fig. 7), following the increasing trend of the electrical resistance of the polarized material as observed by EIS. Thus, the total yields obtained for p-500/aSiO₂, p-800/aSiO₂ and p-1000/aSiO₂ were lower than that achieved for p-150/aSiO₂ by 26%, 88% and 95%, respectively (Fig. 7). It should be remarked that, as predicted in the previous sub-section, p-150/aSiO₂ and p-500/aSiO₂ were the ones that behaved as catalysts, even though the former was more efficient than the latter lower (*i.e.* $786.3 \pm 50.5 \mu\text{mol g}_c^{-1}$ vs. $584.9 \pm 80.8 \mu\text{mol g}_c^{-1}$).

Analysis of the reaction products obtained using p-150/aSiO₂ as catalyst reveals the formation of C1 (formic acid), C2 (acetic acid) and C4 (dioxane) with yields of 313.5 ± 16.9 , 349.1 ± 21.8 and $123.7 \pm 11.7 \mu\text{mol g}_c^{-1}$ (*i.e.* 39.9%, 44.4% and 15.7%, respectively). It is worth mentioning that, although p-150/aSiO₂ behaves as a non-selective catalyst, it is able to promote the formation of C4 products. This was never achieved with p-HAp, independently of the reaction conditions. However, p-HAp was tuned to be selective towards the formation of ethanol and acetic acid (C2), regardless of the reactions parameters, by adapting the set-up used for the thermoelectric polarization.^{14,62} More specifically, the formation of a brushite-like phase was induced at the surface of p-HAp, preferentially giving C2 products, even though a significant amount of C1 (formic acid) and a residual yield of C3 (acetone) were also detected (see below).

On the other hand, the variety of reaction products derived from the process with p-500/aSiO₂ was much higher than that

obtained using p-150/aSiO₂. Specifically, formic acid and dioxane were the only C1 and C4 product, respectively, produced by the reaction with such two catalysts, even though the reaction yields were 5.5 and 8.3 times higher for p-150/aSiO₂ than for p-500/aSiO₂. However, p-500/aSiO₂ promoted the production of acetic acid and ethanol as C2 and isopropanol and acetone as C3. Interestingly, the maximum yields were obtained for ethanol ($215.2 \pm 20.8 \mu\text{mol g}_c^{-1}$) and isopropanol ($258.0 \pm 28.4 \mu\text{mol g}_c^{-1}$), which were not observed for the reaction catalyzed by p-150/aSiO₂.

Overall, results show that p-150/aSiO₂ is a free-metal efficient and, as consequence of both its natural abundance and the relatively low temperature required for its polarization, low-cost and sustainable catalyst. This material is capable of catalyzing the formation of C–C bonds, leading not only to the formation of C2 and C3, but also C4. Although selectivity is still pending, this issue will be addressed in future work following a strategy similar to that followed for p-HAp, which consisted in the activation of the surface by inducing the formation of a more ordered phase during the thermoelectric polarization process.^{14,63}

Comparison between p-150/aSiO₂ and p-HAp

The aim of this sub-section is to quantitatively compare the activity and selectivity of p-150/aSiO₂ and p-HAp catalysts in the conversion of CO₂ to valuable chemical products. For this purpose, batch reactions using experimental conditions identical to those described above for p-150/aSiO₂ (6 bar of CO₂ and 40 mL of water at 120 °C for 72 h) were conducted for p-HAp. It is worth noting that such conditions were never used before for p-HAp catalyst, which was prepared following the procedure reported in the literature.⁶³ The yields of the individual reaction products are displayed in Fig. 8a and Table S3,[†] while the total yields are compared in Fig. 8b.

In general, the yields were much higher for p-150/aSiO₂ than for p-HAp (*i.e.* around 2.8 times in terms of total yield). While the reaction with p-150/aSiO₂ produced similar amounts of formic acid (C1) and acetic acid (C2), the sum of the yields of acetic acid and ethanol was higher than the yield of formic acid in the reaction catalyzed by p-HAp. Thus, the C2 : C1 yields ratio was 1.11 and 1.70 for p-150/aSiO₂ and p-HAp, respectively. On the other hand, the amount of acetone (C3) produced by p-HAp was very low in comparison to the yield of dioxane (C4) in the reaction catalyzed by p-150/aSiO₂, indicating that the C–C coupling is more favored in the latter than in the former.

The main structural and surface characteristics of p-150/aSiO₂ and p-HAp are summarized in Table 3. The BET surface area and the pore size were much higher and smaller (*i.e.* two and one orders of magnitude, respectively) for p-150/aSiO₂ than for p-HAp, which is consistent with the yields displayed in Fig. 8.

In conclusion, the application of thermoelectric treatment to aSiO₂ to convert it into a compound with catalytic activity revealed significant differences with respect to Hap. Thus, catalytic properties of permanently polarized Hap were obtained by orienting the OH– groups and accumulating charge



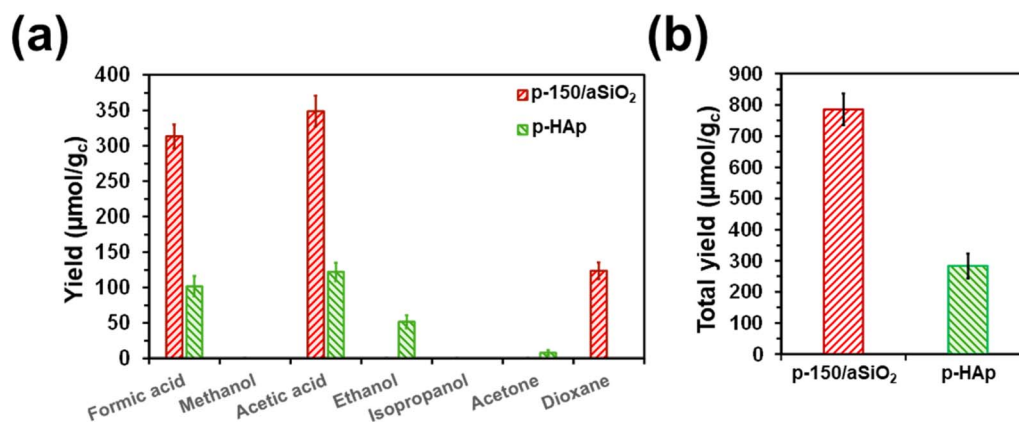


Fig. 8 (a) Variation of the different product yields dissolved in the supernatant and adsorbed in the catalyst from batch reactions catalyzed by p-150/aSiO₂ and p-HAp. (b) Total yield (i.e. sum of all the yields for all the reaction products dissolved in the supernatant and adsorbed on the catalyst) for p-150/aSiO₂ and p-HAp catalysts. Reactions were conducted at 120 °C using 6 bar of CO₂ and 40 mL of liquid water. The yields are expressed in μmol of product per gram of catalyst (μmol g_c⁻¹).

Table 3 BET surface area, pore volume and pore diameter of p-150/aSiO₂ and p-HAp

	p-150/aSiO ₂	p-HAp
BET surface area (m ² g ⁻¹)	445.91	3.87
Pore volume (cm ³ g ⁻¹)	0.413	0.014
Pore diameter (nm)	3.71	14.6

at the intergranular regions,^{14,15} while when applied to aSiO₂ the thermoelectric treatment mainly affects to the superficial Si–OH groups, suggesting a different mechanism for the catalytic transformation of CO₂ in valuable chemical products. The polarization of aSiO₂ was only achieved when the temperature was 150 °C and, to a lesser extent, 500 °C. Future studies will be addressed to compare the catalytic stability of p-150/aSiO and p-HAp, the latter being known to be very stable and easily regenerable.⁶⁴ Although the energy required to polarize aSiO₂ at 150 °C is much lower than that necessary for p-HAp (ideally 1000 °C), the lack of selectivity needs also to be addressed. Thus, p-150/aSiO₂ performs better than p-HAp, in terms of CO₂ fixation but shows a worse performance when selectivity is involved. Therefore, the assessment of the sustainability of p-150/aSiO₂ as a catalyst will depend on the total mass and energy balance specific to each process, as it is necessary to consider the energy required to separate the products derived from said catalytic process. On the other hand, the abundance of aSiO₂ and the fact that no precious or heavy metals need to be added represent a clear advantage in terms of sustainability with respect to metal-based catalysts proposed for CO₂ fixation.

Conclusions

For the first time, the thermoelectric polarization was applied to aSiO₂ to produce catalysts capable of converting CO₂ into valuable chemical products. Unlike what was observed for p-HAp, which required a higher polarization temperature to

induce chemical and structural changes large enough to produce catalytic activity, in the case of p-T/aSiO₂ the greatest changes were obtained when the polarization temperature was 150 °C. Although p-500/aSiO₂ also presented some catalytic activity, much lower than that of p-150/aSiO₂, the activity of p-800/aSiO₂ and p-1000/aSiO₂ was practically null.

The catalytic selectivity of p-150/aSiO₂ under the studied conditions (batch reaction with 6 bar of CO₂ and 40 mL of water at 120 °C) was low in the sense that produced C1 (formic acid), C2 (acetic acid) and C4 (dioxane) products with high yields. Thus, the selectivity towards C1, C2 and C4 was 39.9%, 44.4% and 15.7%, respectively. However, no other products, such as ethanol and acetone, which are typically obtained using p-HAp, were detected. Additionally, it is worth mentioning that no C4 product was ever obtained using p-HAp as catalyst, even though for the latter the number of reaction conditions tested was very extensive.

Overall, this work should be considered as a proof of concept in which we demonstrate that p-150/aSiO₂ is a promising catalyst for the efficient CO₂ catalytic conversion into valuable chemical products and, by extension, also shows the potential of the thermoelectrically polarization treatment towards new material candidates. The most important advantages of this catalyst are the abundance and low cost of the source material, aSiO₂, and the mild conditions required to transform aSiO₂ to p-150/aSiO₂. Thus, the latter should be considered a priori as a sustainable catalyst. Future work will be aimed to refine the properties of p-T/aSiO₂ by examining the influence of the voltage and the process used in the calcination step (i.e. water vapor atmosphere vs. air) to obtain not only the maximum efficiency in continuous reactions but also the optimum selectivity and maximum stability.

Data availability

The data supporting this article have been included as part of the ESI.†



Conflicts of interest

The authors declared that there is no conflict of interest in this work.

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